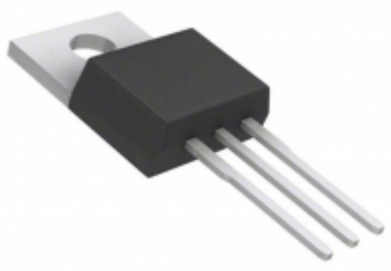


	<h2 style="color: red;">FQP2N60C</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQP2N60C
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 600V 2A TO-220
	Datenblätter: <ul style="list-style-type: none">  1.FQP2N60C.pdf  2.FQP2N60C.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 19930 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQP2N60C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 600V 2A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	19930 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	54W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2A (Tc)
Rds On (Max) @ Id, Vgs	4.7 Ohm @ 1A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	235pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































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Anfrage FQP2N60C: Info@Y-IC.com

Sie können auch interessiert sein:

 FQP2N60 Fairchild/ON Semiconductor MOSFET N-CH 600V 2.4A TO-220	 FQP2N80 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 2.4A TO-220	 FQP2N60C AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2A TO-220	 FQP2N65C VB FQP2N65C VB
 FQP2N70 FSC FQP2N70 FSC	 FQP2N60 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2.4A TO-220	 FQP2N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 2.1A TO-220	 FQP2N90 Fairchild/ON Semiconductor MOSFET N-CH 900V 2.2A TO-220

heiße Teile

Mehr

 FQP19N20C	 FQP19N20L	 FQP19N20L	 FQP1N60C	 FQP20N06
 FQP20N06	 FQP20N06L	 FQP20N06L	 FQP20N06TSTU	 FQP20N06TSTU
 FQP20N60	 FQP22N30	 FQP22N30	 FQP22P10	 FQP22P10
 FQP24N08	 FQP24N08	 FQP24N40	 FQP27N25	 FQP27N25
 FQP27N60	 FQP27P06	 FQP27P06	 FQP2N60B	 FQP2N60C
 FQP2N65C	 FQP30N06	 FQP30N06	 FQP30N06L	 FQP30N06L
 FQP32N12V2	 FQP32N12V2	 FQP32N20	 FQP32N20C	 FQP32N20C
 FQP33N10	 FQP33N10	 FQP33N10L	 FQP33N10L	 FQP34N20
 FQP34N20	 FQP34N20L	 FQP34N20L	 FQP3N50C	 FQP3N60C
 FQP3N60C	 FQP3N80C	 FQP3N80C	 FQP44N08	 FQP44N08

Contact us: Info@Y-IC.com

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